MTM232270LBF

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Silicon N-channel MOSFET

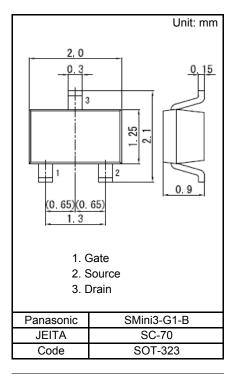
For switching

MTM13227 in SMini3 type package

Features

- Low drain-source ON resistance:RDS(on) typ. = 85 m Ω (VGS = 4.0 V)
- Low drive voltage: 2.5 V drive
- Halogen-free / RoHS compliant
- (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: ET

Packaging
MTM232270LBF Embossed type (Thermo-compression sealing):
3 000 pcs / reel (standard)



Internal Connection 3 1 2 Pin name 1. Gate 2. Source 3. Drain

■ Absolute Maximum Ratings Ta = 25 °C

		-	
Parameter	Symbol	Rating	Unit
Drain-source Voltage	VDS	20	V
Gate-source Voltage	VGS	±10	V
Drain current	ID	2.0	Α
Drain Current (Pulsed) ^{*1}	IDp	8	Α
Total Power Dissipation *2	PD	500	mW
Channel Temperature	Tch	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Note: *1 Pulse width \leq 10 μ s, Duty cycle \leq 1%

*2 Measuring on ceramic board at 40 mm \times 38 mm \times 0.1 mm. Absolute maximum rating PD without heat sink shall be made 150 mW.

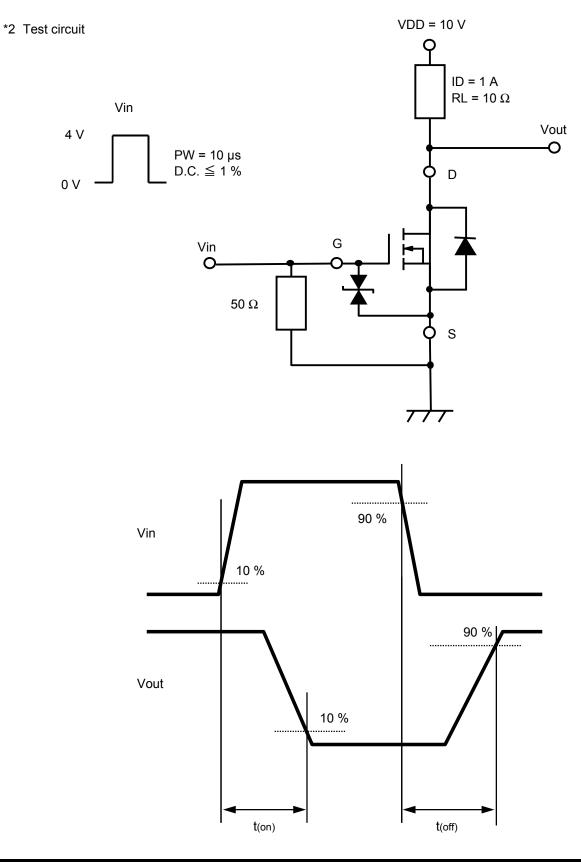
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = 1 mA, VGS = 0 V	20			V
Zero Gate Voltage Drain Current	IDSS	VDS = 20 V, VGS = 0 V			10	μA
Gate-source Leakage Current	IGSS	VGS = ±8 V, VDS = 0 V			±10	μA
Gate-source Threshold Voltage	Vth	ID = 1.0 mA, VDS = 10 V	0.4	0.85	1.3	V
Drain to Source On-State Resistance *1	RDS(on)1	ID = 1 A, VGS = 4 V		85	110	mΩ
	RDS(on)2	ID = 0.5 A, VGS = 2.5 V		100	150	
Forward transfer admittance *1	Yfs	ID = 1 A, VDS = 10 V, f = 1 kHz	3.0			S
Input Capacitance	Ciss			290		pF
Output Capacitance	Coss	VDS = 10 V, VGS = 0, f = 1 MHz		26		
Reverse Transfer Capacitance	Crss			20		
Turn-on Time ^{*2}	ton	VDD = 10 V, VGS = 0 to 4 V, ID = 1 A		12		ns
Turn-off Time ^{*2}	toff	VDD = 10 V, VGS = -4 to 0 V, ID = 1 A		60		ns

■ Electrical Characteristics Ta = 25°C±3°C

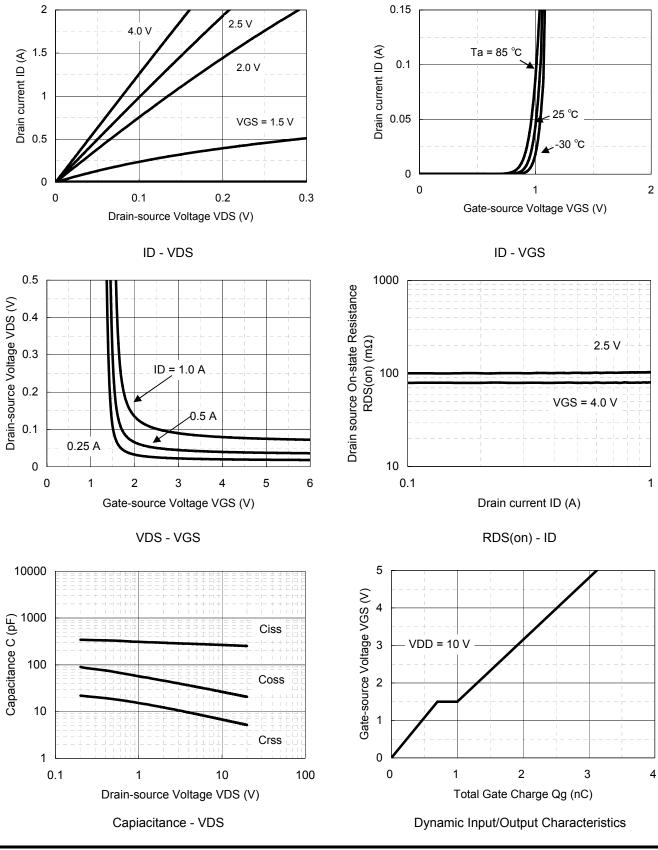
Note: Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

*1 Pulse test : Pulse width \leq 10 μs , Duty cycle \leq 1 %

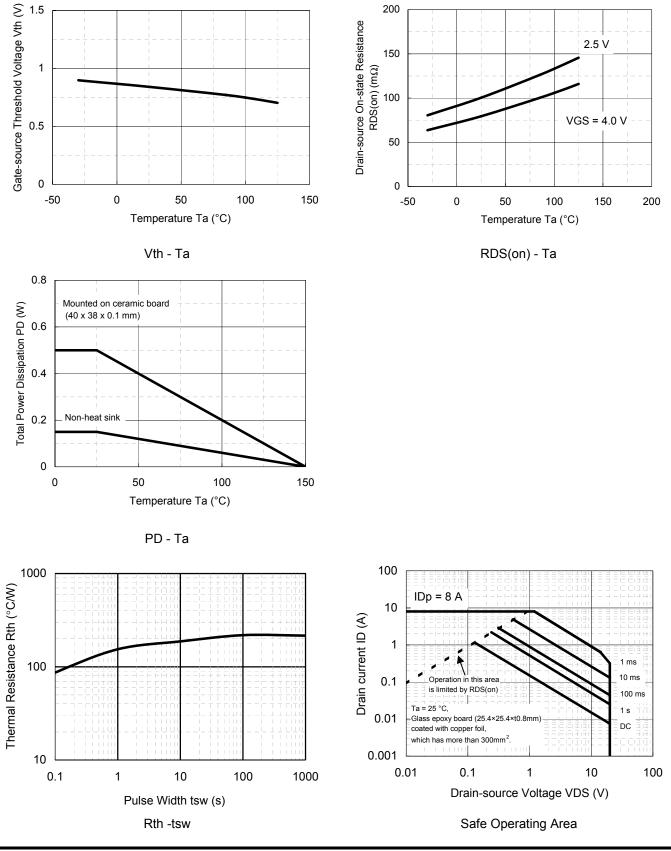
*2 See test circuit

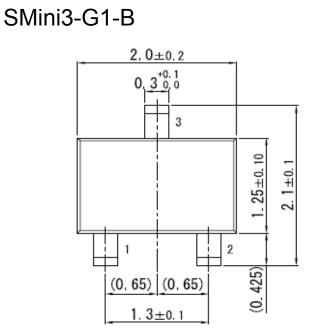


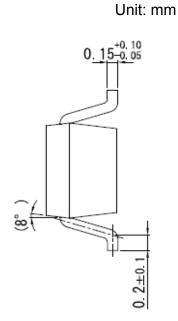
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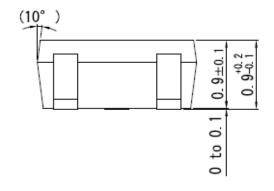


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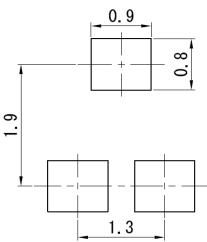








■ Land Pattern (Reference) (Unit: mm)



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